Supplementary Information

Trap Passivation and Efficiency Improvement of Perovskite Solar Cells by a Guanidinium Additive

Jiaxu Yao\textsuperscript{a,b}, Hui Wang\textsuperscript{a,b}, Pang Wang\textsuperscript{a,b}, Robert S. Gurney\textsuperscript{a,b}, Akarin Intaniwet\textsuperscript{c},

Pipat Ruankham\textsuperscript{d}, Supab Choopun\textsuperscript{d}, Dan Liu\textsuperscript{a,b}\textsuperscript{*}, Tao Wang\textsuperscript{a,b}\textsuperscript{*}

\textsuperscript{a}State Key Laboratory of Silicate Materials for Architectures, Wuhan University of Technology, Wuhan, 430070, China * E-mail: dliu@whut.edu.cn; twang@whut.edu.cn

\textsuperscript{b}School of Materials Science and Engineering, Wuhan University of Technology, Wuhan, 430070, China

\textsuperscript{c}Smart Energy and Environment Research Unit, School of Renewable Energy, Maejo University, Chiang Mai 50290, Thailand

\textsuperscript{d}Department of Physics and Materials Science, Faculty of Science, Chiang Mai University, Chiang Mai 50200, Thailand
Figure S1. The storage life time of devices without and with 0.6 wt% DAGCl additive.

Figure S2 (a,b) Surface-view SEM images of perovskite films without and with the optimized concentration of DAGCl additive. c) The statistic plot of grains size based on images a and b.
Figure S3. (a) XRD spectra of perovskite films containing different contents of DAGCl. (b) XRD spectra of films cast from precursors containing DAGCl and PbI$_2$. 
Figure S4. (a) and (b) EIS measurements by applying a low voltage (0.2 v) and high voltage (1.0 v), under 1-sun illumination, without and with the optimized concentration of DAGCl additive.
Figure S5. Bode plot and Nyquist plot of PSC without additive (a, b) and with 0.6 wt% DAGCl (c, d) from IMVS testing, respectively. e) The voltage changes at different light intensity during an IMVS test.

Figure S6. Dark current–voltage curves of electron-only devices employing an n-type semiconductor PDI$_2$ to replace PCBM.